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DT09 Rec'd PCT/PTO 20 AUG 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Hideo HOSONO et al.

Serial Number: Not Yet Assigned
(§371 of international application No.: PCT/JP03/01756)

Filed: August 20, 2004

For: LnCuO(S, Se, Te) SINGLE-CRYSTAL THIN FILM, PRODUCTION METHOD
THEREOF, AND OPTICAL OR ELECTRONIC DEVICE USING
THE SINGLE-CRYSTAL THIN FILM

Attorney Docket No.: 042112
Customer No.: 38834

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P. O. Box 1450
Alexandria, VA 22313-1450

August 20, 2004

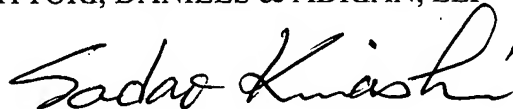
Sir:

In compliance with 37 CFR 1.56, Applicant(s) call(s) to the attention of the Patent and Trademark Office the references listed on the attached PTO-1449. References AA-AD are cited in the enclosed international search report.

A copy of each of the references is enclosed herewith

In the event there are any fees due in connection with the filing of this paper, please charge Deposit Account No. 50-2866.

Respectfully submitted,
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Enclosures: PTO-1449; International Search Report w/ 10 references.

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INFORMATION DISCLOSURE STATEMENT PTO-1449	Attv. Docket No. 042112	Serial No. New Appln.
	Applicant(s): Hideo HOSONO et al.	
	Filing Date: August 20, 2004	Group Art Unit:

FOREIGN PATENT DOCUMENTS

Document No.						Date	Country	Translation (Yes or No)
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Examiner

Date Considered